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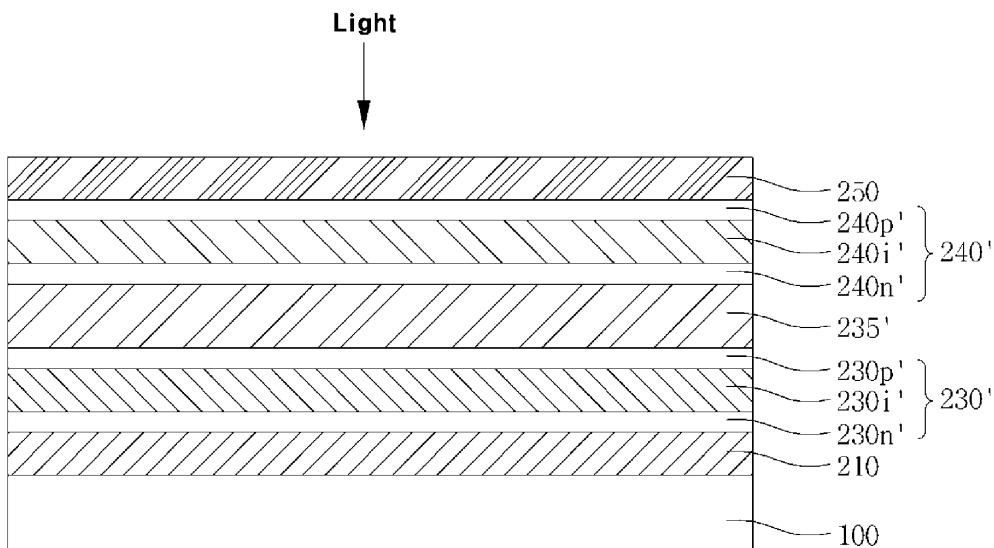
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(54) Photovoltaic device and method for manufacturing the same

(57) Disclosed is a method for manufacturing a photovoltaic device. The method includes: forming a first electrode on a substrate; forming a first unit cell on the first electrode, the first unit cell comprising an intrinsic semiconductor layer; forming an intermediate reflector on the first unit cell, the intermediate reflector comprises

a plurality of sub-layers stacked alternately by modulating the applied voltages in accordance with time, the applied voltages exciting plasma and having mutually different frequencies; forming a second unit cell on the intermediate reflector, the second unit cell comprising an intrinsic semiconductor layer; and forming a second electrode on the second unit cell.

【 Fig.6】





EUROPEAN SEARCH REPORT

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A	* paragraphs [0010], [0012] - [0014], [0024] - [0029], [0030] - [0034]; figure 1 *	1-14	H01L31/052 H01L31/075 H01L27/142
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			H01L
The present search report has been drawn up for all claims			
1	Place of search Berlin	Date of completion of the search 14 September 2012	Examiner Pantelidis, D
CATEGORY OF CITED DOCUMENTS		T : theory or principle underlying the invention E : earlier patent document, but published on, or after the filing date D : document cited in the application L : document cited for other reasons & : member of the same patent family, corresponding document	
X : particularly relevant if taken alone Y : particularly relevant if combined with another document of the same category A : technological background O : non-written disclosure P : intermediate document			



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**ANNEX TO THE EUROPEAN SEARCH REPORT
ON EUROPEAN PATENT APPLICATION NO.**

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This annex lists the patent family members relating to the patent documents cited in the above-mentioned European search report. The members are as contained in the European Patent Office EDP file on The European Patent Office is in no way liable for these particulars which are merely given for the purpose of information.

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